
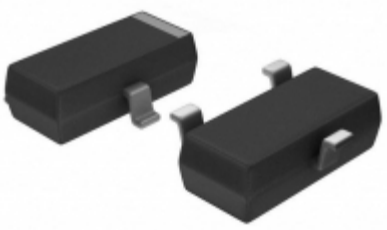
	<p>SI2399DS-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI2399DS-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 6A SOT-23</p> <p>Datenblätter:  SI2399DS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 101345 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2399DS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 6A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	101345 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 2.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A (Tc)
Rds On (Max) @ Id, Vgs	34 mOhm @ 5.1A, 10V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	835pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 10V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)


















































SI2399DS-T1-GE3 ist neu im Original, Suche SI2399DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2399DS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2399DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2400-BS Energy Micro (Silicon Labs) IC ISODEM SYSTEM-SIDE 16SOIC</p>	 <p>SI2400-FSR SILCO SI2400-FSR SILCO</p>	 <p>SI2400-FS Energy Micro (Silicon Labs) IC ISODEM SYST-SIDE DAA 16SOIC</p>	 <p>SI2400-KSR SI SI2400-KSR SI</p>
 <p>SI2399 SIPU SI2399 SIPU</p>	 <p>SI2399DS-T1-E3 Son SI2399DS-T1-E3 Son</p>	 <p>SI2399CDS-T1-GE3 V SI2399CDS-T1-GE3 V</p>	 <p>SI2399DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 6A SOT-23</p>

heiße Teile

Mehr

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|--|--|--|---|--|
|  SI2366DS-T1-GE3 |  SI2366DS-T1-GE3 |  SI2367DS-T1-E3 |  SI2367DS-T1-GE3 |  SI2367DS-T1-GE3 |
|  SI2369DS-T1-GE3 |  SI2369DS-T1-GE3 |  SI2371EDS-T1-GE3 |  SI2371EDS-T1-GE3 |  SI2372DS-T1-E3 |
|  SI2372DS-T1-GE3 |  SI2372DS-T1-GE3 |  SI2374DS-T1-GE3 |  SI2374DS-T1-GE3 |  SI2377DS-T1-GE3 |
|  SI2377EDS |  SI2377EDS-T1-E3 |  SI2377EDS-T1-GE3 |  SI2377EDS-T1-GE3 |  SI2392ADS-T1-E3 |
|  SI2392ADS-T1-GE3 |  SI2392ADS-T1-GE3 |  SI2392DS-T1-GE3 |  SI2392DS-T1-GE3 |  SI2399CDS-T1-GE3 |
|  SI2399DS-T1-GE3 |  SI2400-BS |  SI2400-FS |  SI2400-FSR |  SI2400-KS |
|  SI2400-KSR |  SI2401-FS |  SI2401-FSR |  SI2401-FSR. |  SI2401-KS |
|  SI2403-FTR |  SI2404-C-FSR |  SI2404-C-FTR |  SI2404-C-ZSR |  SI2404-CFTRP |
|  SI2404-FS |  SI2404-FT |  SI2413AP |  SI2414-F-FTR |  SI2414-FT |
|  SI2414-FTR |  SI2414-KT |  SI2415-C-FT |  SI2415-FS |  SI2415-FT |

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